

PMN55ENE 60 V, N-channel Trench MOSFET 14 December 2017

Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Trench MOSFET technology •
- Logic-level compatible
- Very fast switching •
- ElectroStatic Discharge (ESD) protection > 2 kV HBM •

3. Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	60	V
V _{GS}	gate-source voltage			-20	-	20	V
I _D	drain current	V_{GS} = 10 V; T_{amb} = 25 °C; t ≤ 5s	[1]	-	-	4.5	А
Static charact	Static characteristics						
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I _D = 3.4 A; T _j = 25 °C		-	46	60	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

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5. Pinning information

Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol			
1	D	drain		D			
2	D	drain					
3	G	gate		G ← ← ↓ ☆ 入			
4	S	source	TSOP6 (SOT457)				
5	D	drain					
6	D	drain		' S			
				017aaa255			

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
PMN55ENE	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457			

7. Marking

Table 4. Marking codes	
Type number	Marking code
PMN55ENE	3J

8. Limiting values

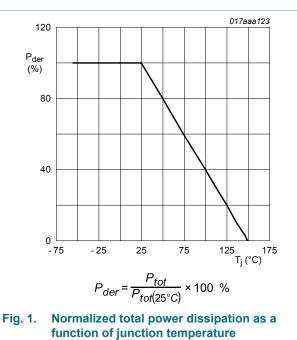
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	60	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5s	[1]	-	4.5	А
		V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	3.4	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	2.2	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	14	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	560	mW
			[1]	-	1.4	W
		T _{sp} = 25 °C		-	6.25	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source Drai	n Diode					
l _S	source current	T _{amb} = 25 °C	[1]	-	1.4	А

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

[2] Device mounted on an FR4 PCB, single-sided copper; tin-plated and standard footprint.



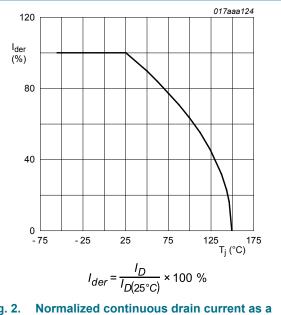
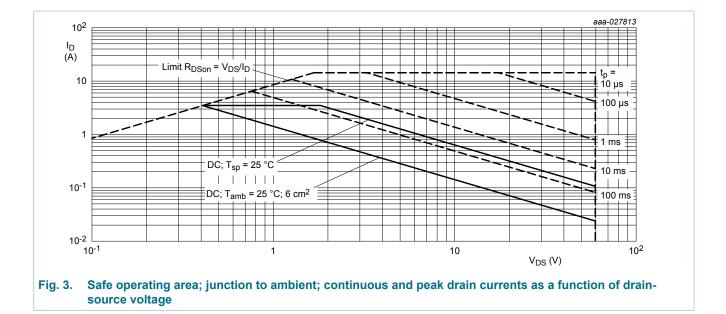


Fig. 2. Normalized continuous drain curren function of junction temperature

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9. Thermal characteristics

Table 6. Thermal characteristics

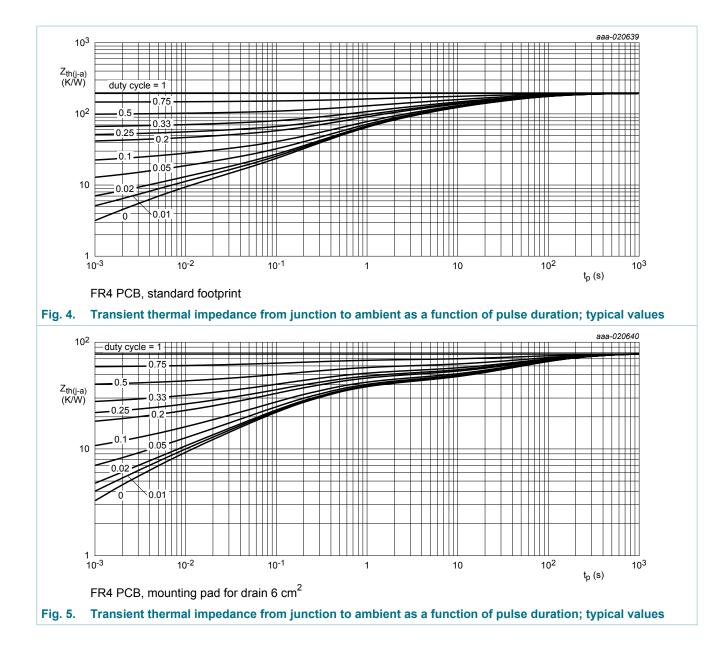
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	-	[1]	-	195	225	K/W
			[2]	-	78	90	K/W
		in free air; t = 5s	[2]	-	55	63	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	15	20	K/W

[1] Device mounted on an FR4 PCB, single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².

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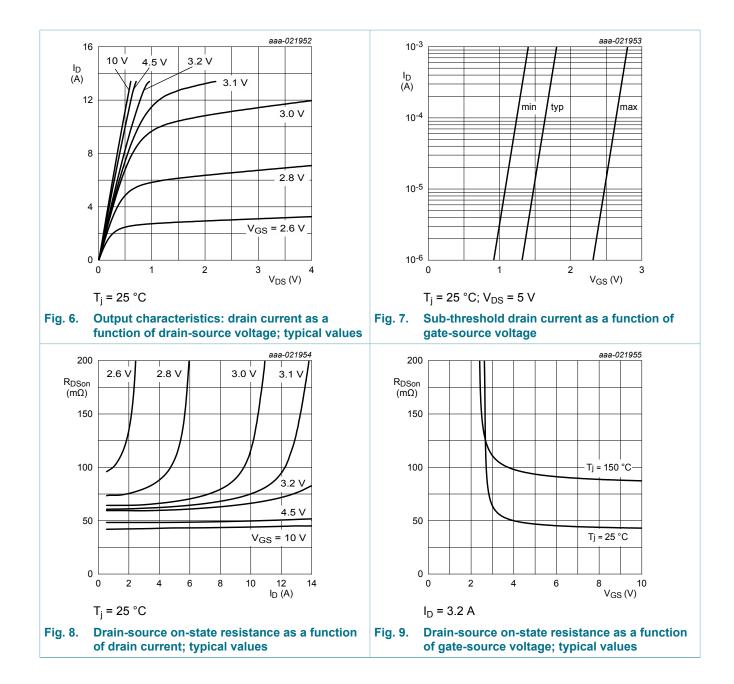


10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	1				
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	60	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	1.3	1.7	2.7	V
I _{DSS}	drain leakage current	V _{DS} = 60 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
I _{GSS} ga	gate leakage current	V _{GS} = 20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μA
		V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	-	1	μA
		V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-1	μA
R _{DSon} drain-source on-state	drain-source on-state	V _{GS} = 10 V; I _D = 3.4 A; T _j = 25 °C	-	46	60	mΩ
resista	resistance	V _{GS} = 10 V; I _D = 3.4 A; T _j = 150 °C	-	92	120	mΩ
		V _{GS} = 4.5 V; I _D = 3.2 A; T _j = 25 °C	-	52	70	mΩ
9 _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 3.1 A; T _j = 25 °C	-	18.2	-	S
R _G	gate resistance	f = 1 MHz	-	8	-	Ω
Dynamic ch	naracteristics		1			
Q _{G(tot)}	total gate charge	V_{DS} = 30 V; I _D = 3.1 A; V _{GS} = 10 V;	-	12.7	19	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	1.3	-	nC
Q _{GD}	gate-drain charge		-	2.4	-	nC
C _{iss}	input capacitance	V _{DS} = 30 V; f = 1 MHz; V _{GS} = 0 V;	-	646	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	49	-	pF
C _{rss}	reverse transfer capacitance		-	36	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = 30 V; I _D = 3.1 A; V _{GS} = 10 V;	-	9	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	13	-	ns
t _{d(off)}	turn-off delay time	1	-	33	-	ns
t _f	fall time		-	13	-	ns
Source-drai	in diode	·				
V _{SD}	source-drain voltage	I _S = 1.4 A; V _{GS} = 0 V; T _i = 25 °C	-	0.8	1.2	V

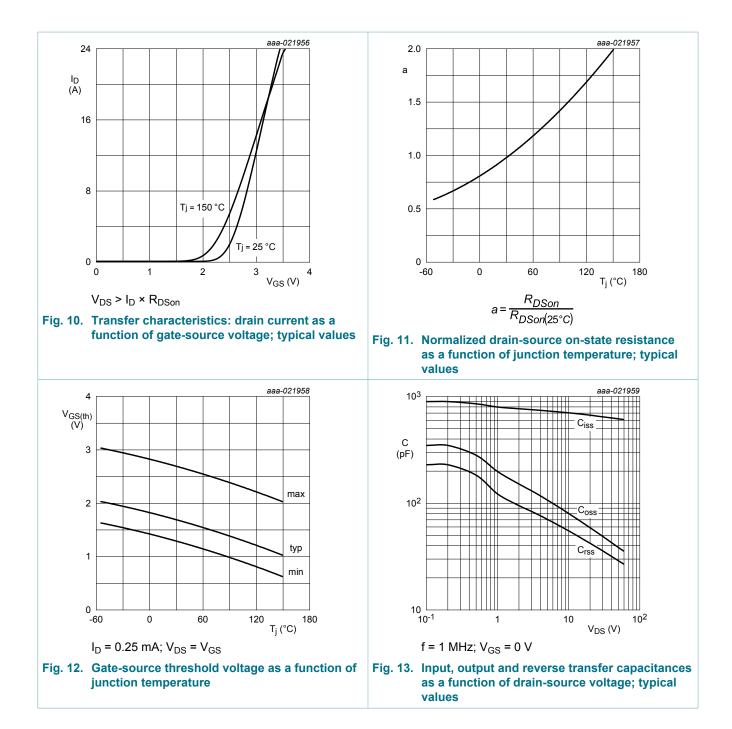
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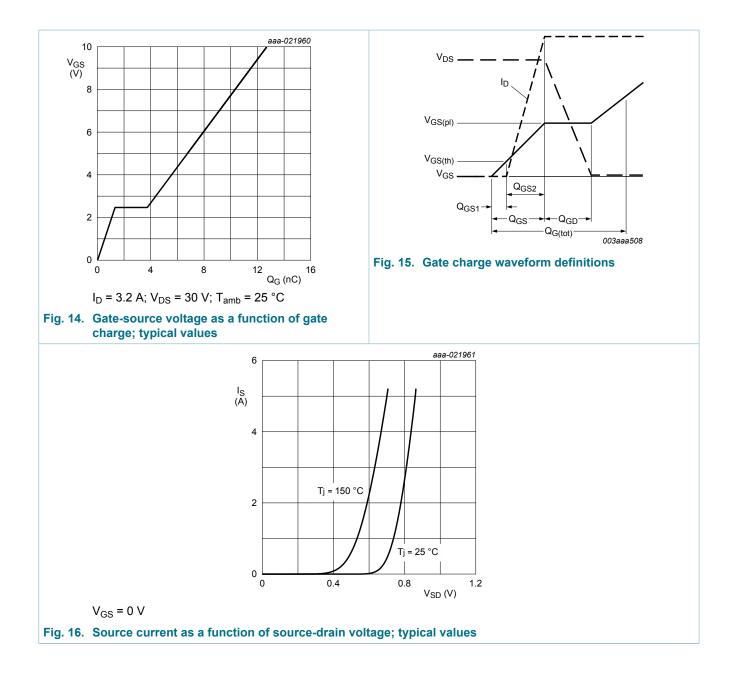
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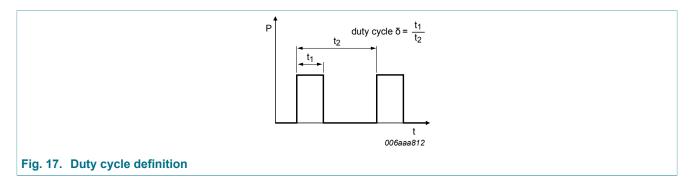


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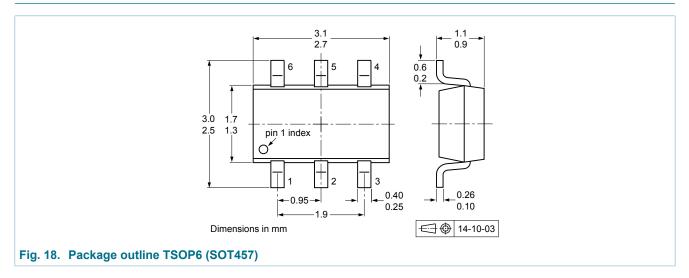
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11. Test information

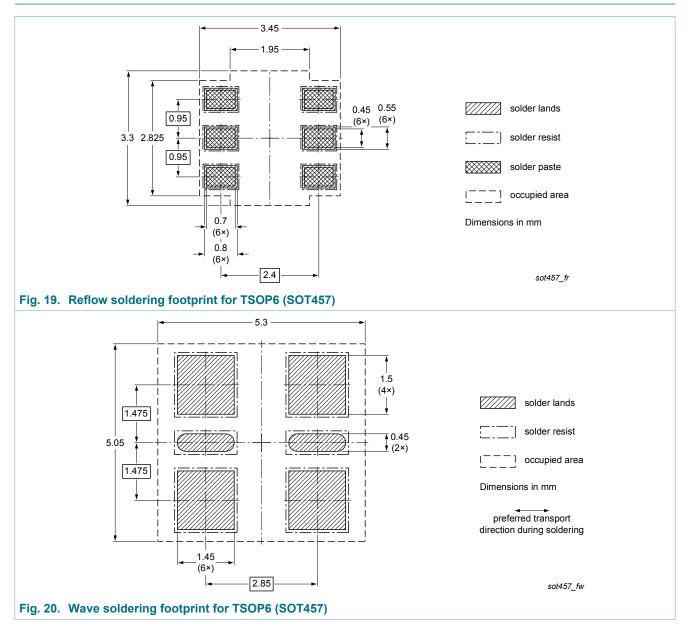


12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMN55ENE v.1.	20171214	Product data sheet	-	-		

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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